

# CMS45N10H8-HF

N-Channel  
RoHS Device  
Halogen Free



## Features

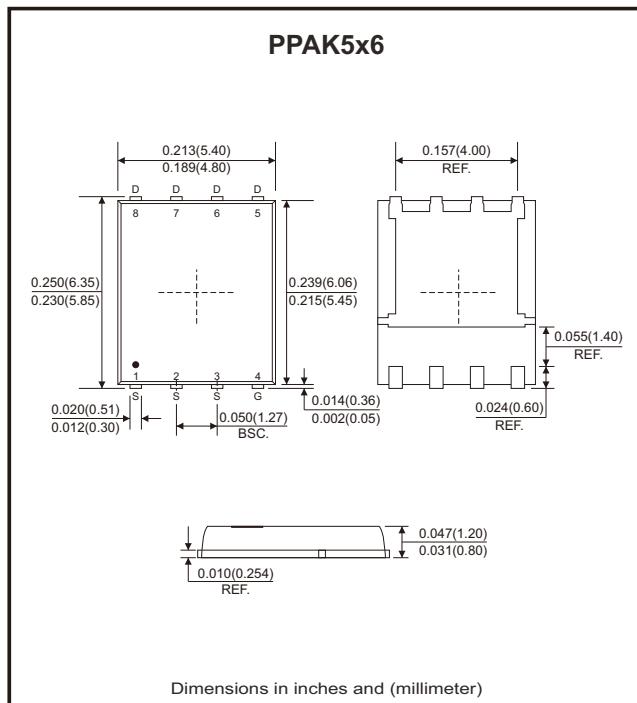
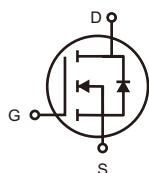
- Improved dv/dt capability.
- Fast switching.
- $R_{DS(ON)} \leq 20\text{m}\Omega$  @  $V_{GS} = 10\text{V}$ .

## Mechanical data

- Case: PPAK5x6, molded plastic.
- Mounting position: Any.

## Circuit Diagram

- G : Gate  
- S : Source  
- D : Drain



## Maximum Ratings (at $T_C=25^\circ\text{C}$ unless otherwise noted)

Parameter	Conditions	Symbol	Value	Unit
Drain-source voltage		$V_{DS}$	100	V
Gate-source voltage		$V_{GS}$	$\pm 20$	V
Drain current-continuous	$T_C = 25^\circ\text{C}$	$I_D$	45	A
Drain current-pulsed	(Note 1)	$I_{DM}$	135	A
Single pulse avalanche energy	(Note 2)	$E_{AS}$	57	mJ
Power dissipation	$T_C = 25^\circ\text{C}$	$P_D$	94.7	W
Thermal resistance junction-ambient		$R_{\theta JA}$	62	$^\circ\text{C}/\text{W}$
Thermal resistance junction-case		$R_{\theta JC}$	1.32	$^\circ\text{C}/\text{W}$
Operating junction temperature range		$T_J$	-55 to +150	$^\circ\text{C}$
Storage temperature range		$T_{STG}$	-55 to +150	$^\circ\text{C}$

**Electrical Characteristics** (at  $T_J=25^\circ\text{C}$  unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-source breakdown voltage	$\text{BV}_{\text{DSS}}$	$\text{V}_{\text{GS}} = 0\text{V}, \text{I}_D = 250\mu\text{A}$	100			V
Drain-source leakage current	$\text{I}_{\text{DSS}}$	$\text{V}_{\text{DS}} = 100\text{V}, \text{V}_{\text{GS}} = 0\text{V}$			1	$\mu\text{A}$
Gate-source leakage current	$\text{I}_{\text{GSS}}$	$\text{V}_{\text{GS}} = \pm 20\text{V}, \text{V}_{\text{DS}} = 0\text{V}$			$\pm 100$	nA
<b>On Characteristics</b>						
Static drain-source on-resistance	$\text{R}_{\text{DS(on)}}$	$\text{V}_{\text{GS}} = 10\text{V}, \text{I}_D = 10\text{A}$			20	$\text{m}\Omega$
		$\text{V}_{\text{GS}} = 4.5\text{V}, \text{I}_D = 7\text{A}$			26	
Gate threshold voltage	$\text{V}_{\text{GS(th)}}$	$\text{V}_{\text{GS}} = \text{V}_{\text{DS}}, \text{I}_D = 250\mu\text{A}$	1.2	1.5	2.5	V
<b>Dynamic and Switching Characteristics</b>						
Total gate charge	$\text{Q}_g$	$\text{V}_{\text{DS}} = 50\text{V}, \text{V}_{\text{GS}} = 10\text{V}, \text{I}_D = 5\text{A}$		16.2		nC
Gate-source charge	$\text{Q}_{\text{gs}}$			2.8		
Gate-drain charge	$\text{Q}_{\text{gd}}$			4.1		
Turn-on delay time	$\text{t}_{\text{d(on)}}$	$\text{V}_{\text{DS}} = 50\text{V}, \text{V}_{\text{GS}} = 10\text{V}, \text{R}_G = 10\Omega, \text{I}_D = 5\text{A}$		16.6		nS
Rise time	$\text{t}_r$			3.8		
Turn-off delay time	$\text{t}_{\text{d(off)}}$			75.5		
Fall time	$\text{t}_f$			46		
Input capacitance	$\text{C}_{\text{iss}}$	$\text{V}_{\text{DS}} = 50\text{V}, \text{V}_{\text{GS}} = 0\text{V}, \text{F} = 100\text{kHz}$		1003.9		pF
Output capacitance	$\text{C}_{\text{oss}}$			185.4		
Reverse transfer capacitance	$\text{C}_{\text{rss}}$			9.8		
<b>Drain-Source Diode Characteristics and Ratings</b>						
Diode forward current	$\text{I}_s$	$\text{V}_{\text{GS}} < \text{V}_{\text{th}}$		30		A
Pulsed source current	$\text{I}_{\text{sp}}$	$\text{V}_G = \text{V}_D = 0\text{V}$ , Force current		90		A

Notes: 1. Pulse width limited by maximum junction temperature.

2.  $\text{V}_{\text{DD}}=50\text{V}, \text{R}_G=25\Omega, \text{L}=0.3\text{mH}$ , starting  $\text{T}_J=25^\circ\text{C}$ .

3. The data tested by pulsed, pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$ .

## Rating and Characteristic Curves (CMS45N10H8-HF)

Fig.1 - Output Characteristics

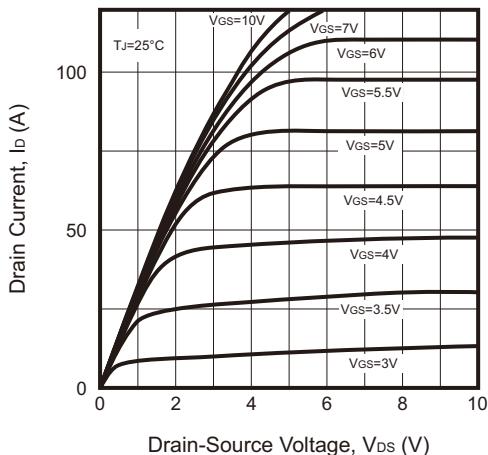


Fig.2 - Transfer Characteristics

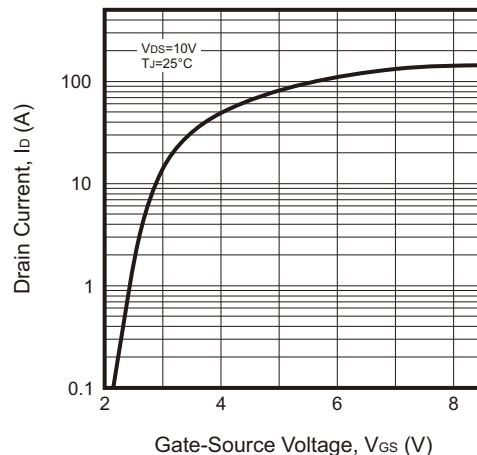


Fig.3 - Gate Charge Characteristics

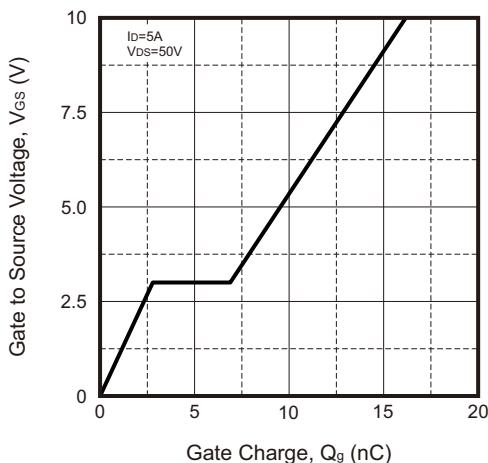


Fig.4 - Drain-Source Breakdown Voltage

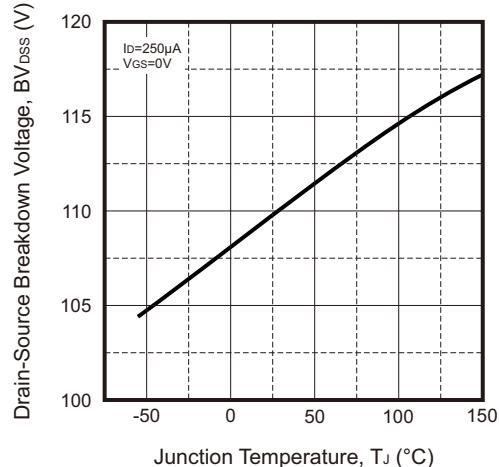


Fig.5 - Drain-Source On-State Resistance

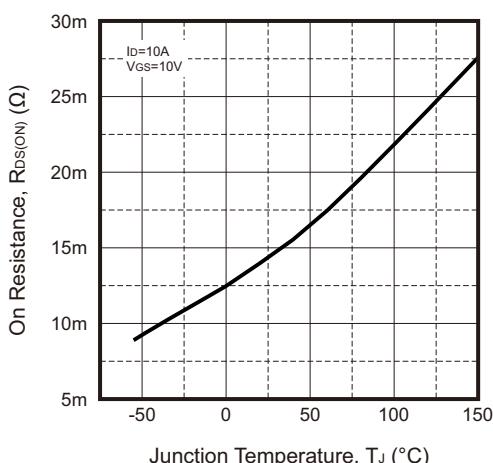
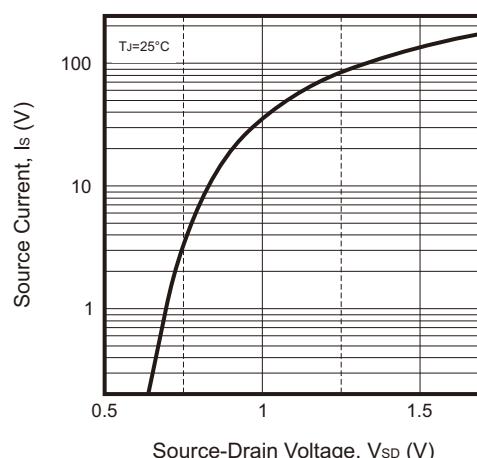
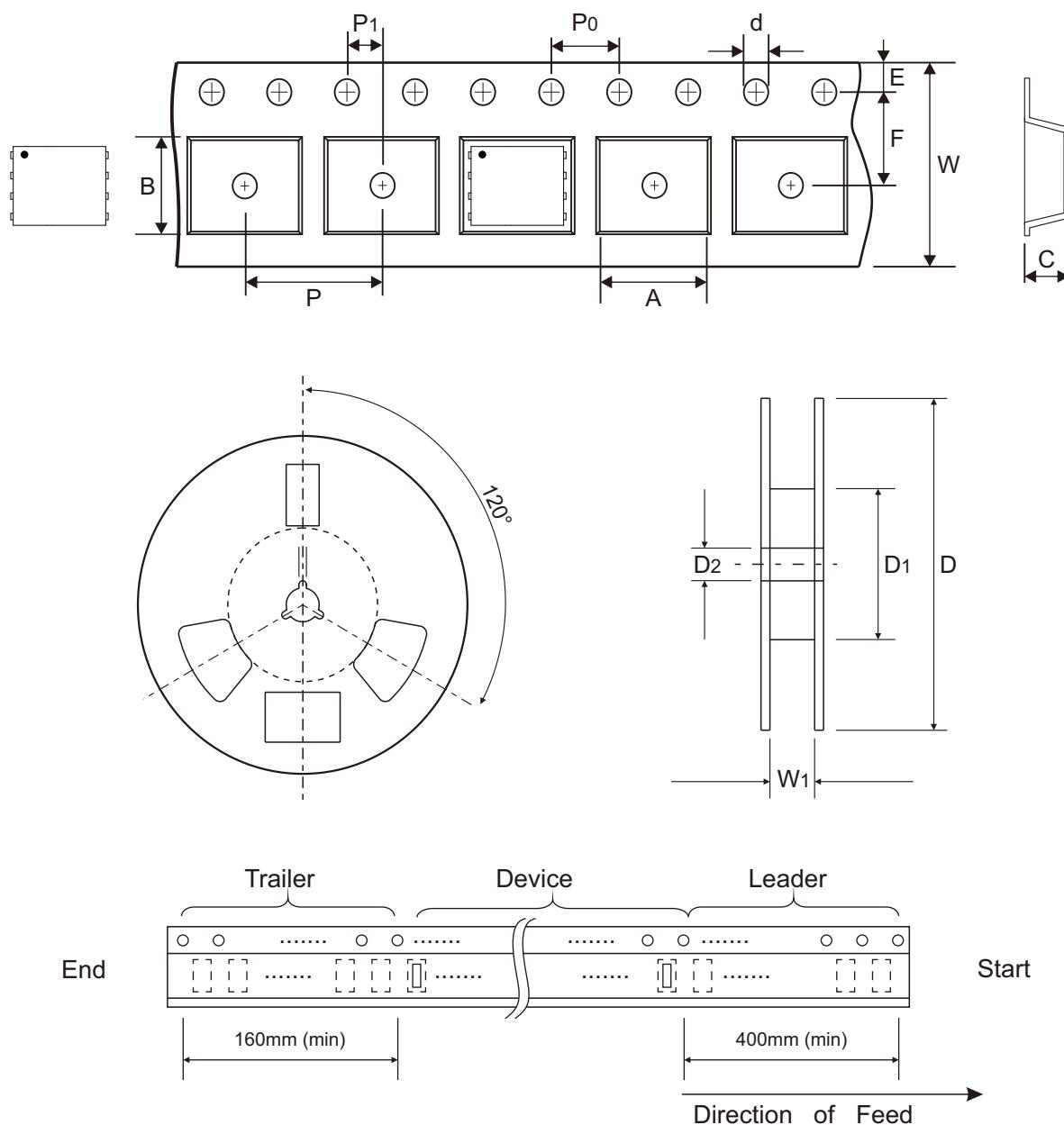


Fig.6 - Forward Characteristic of Body Diode



## Reel Taping Specification



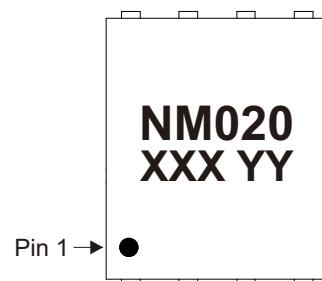
	SYMBOL	A	B	C	d	D	D <sub>1</sub>	D <sub>2</sub>
PPAK5x6	(mm)	$6.50 \pm 0.10$	$5.39 \pm 0.21$	$1.65 \pm 0.45$	$1.50 + 0.10$	$330 \pm 4.00$	95.00 Min	$13.00 \pm 0.50$
	(inch)	$0.256 \pm 0.004$	$0.212 \pm 0.008$	$0.065 \pm 0.018$	$0.059 + 0.004$	$12.992 \pm 0.157$	3.740 Min	$0.512 \pm 0.020$

	SYMBOL	E	F	P	P <sub>0</sub>	P <sub>1</sub>	W	W <sub>1</sub>
PPAK5x6	(mm)	$1.75 \pm 0.10$	$5.50 \pm 0.10$	$8.00 \pm 0.10$	$4.00 \pm 0.10$	$2.00 \pm 0.05$	$12.00 \pm 0.30$	$12.45 \pm 2.05$
	(inch)	$0.069 \pm 0.004$	$0.217 \pm 0.004$	$0.315 \pm 0.004$	$0.157 \pm 0.004$	$0.079 \pm 0.002$	$0.472 \pm 0.012$	$0.490 \pm 0.081$

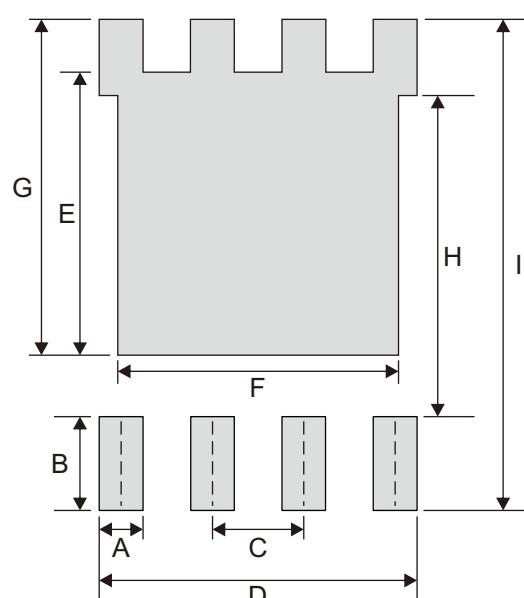
## Marking Code

Part Number	Marking Code
CMS45N10H8-HF	NM020



## Suggested P.C.B. PAD Layout

SIZE	PPAK5x6	
	(mm)	(inch)
A	0.61	0.024
B	1.27	0.050
C	1.27	0.050
D	4.42	0.174
E	3.81	0.150
F	3.91	0.154
G	4.52	0.178
H	4.32	0.170
I	6.61	0.260



## Standard Packaging

Case Type	REEL PACK	
	REEL (pcs)	Reel Size (inch)
PPAK5x6	3,000	13